

**Silica direct evaporation: A size-controlled approach to SiC/carbon nanosheet
composites as Pt catalyst support for superior methanol electrooxidation**

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Table S1. The synthetic conditions for all the compared samples.

Samples	Synthetic conditions	Heating temperature (°C)
SiC/GC (also called as SiC/GC-1400)	ceramic chip	1400
SiC/GC-1300	ceramic chip	1300
SiC/GC-1500	ceramic chip	1500
GC	without ceramic chip	1400
SiC/C	The CS without treating by FeCl ₃	1400

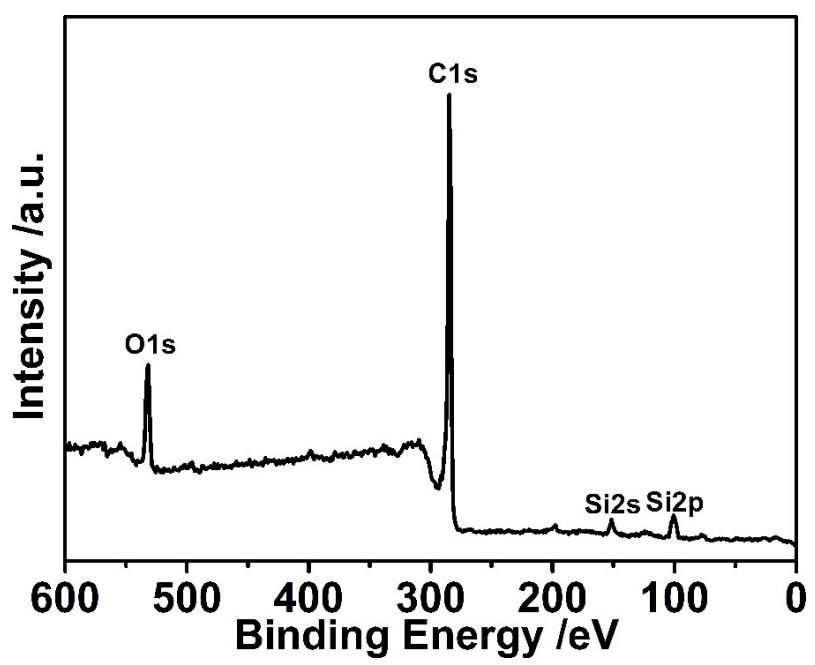


Fig. S1 Wide XPS spectrum of SiC/GC composite.

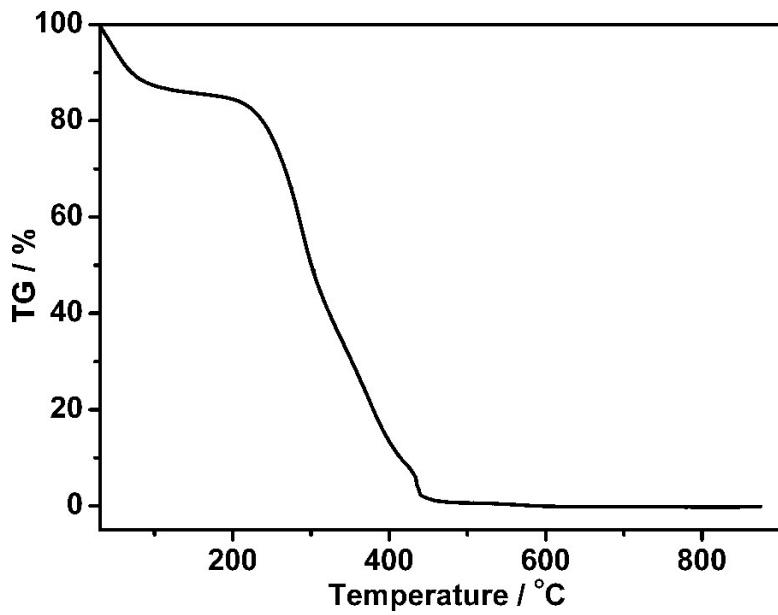


Fig. S2 TG analysis of CS raw material under air.

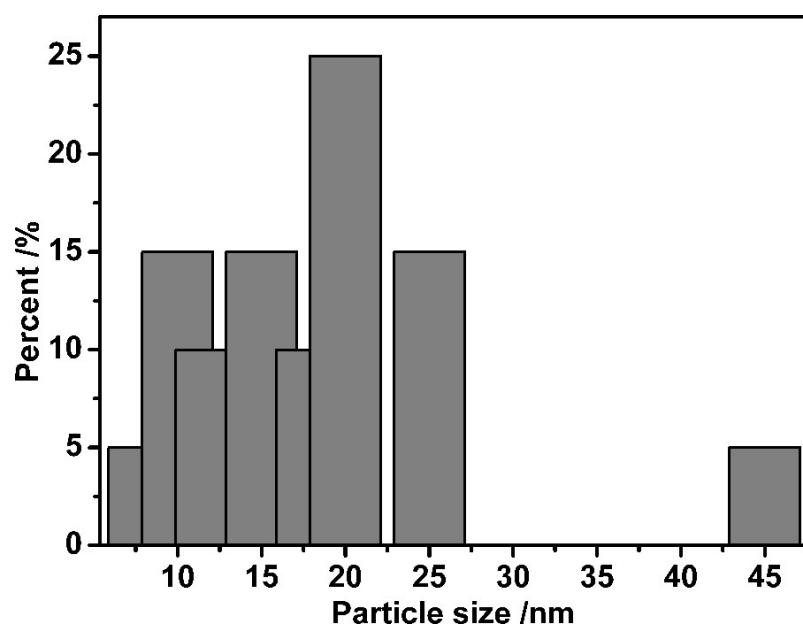


Fig. S3 The corresponding Pt NPs size-distributed graph calculated from Fig. 2A.

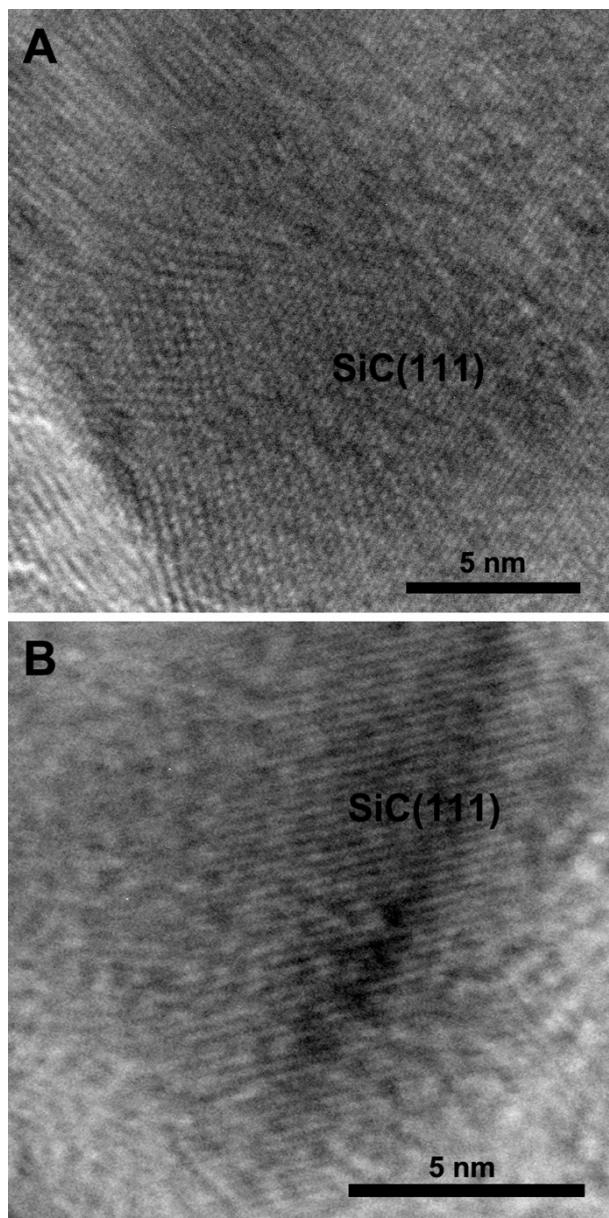


Fig. S4 A, B are the corresponding HRTEM images of Fig. 2C and Fig. 2D,
respectively.

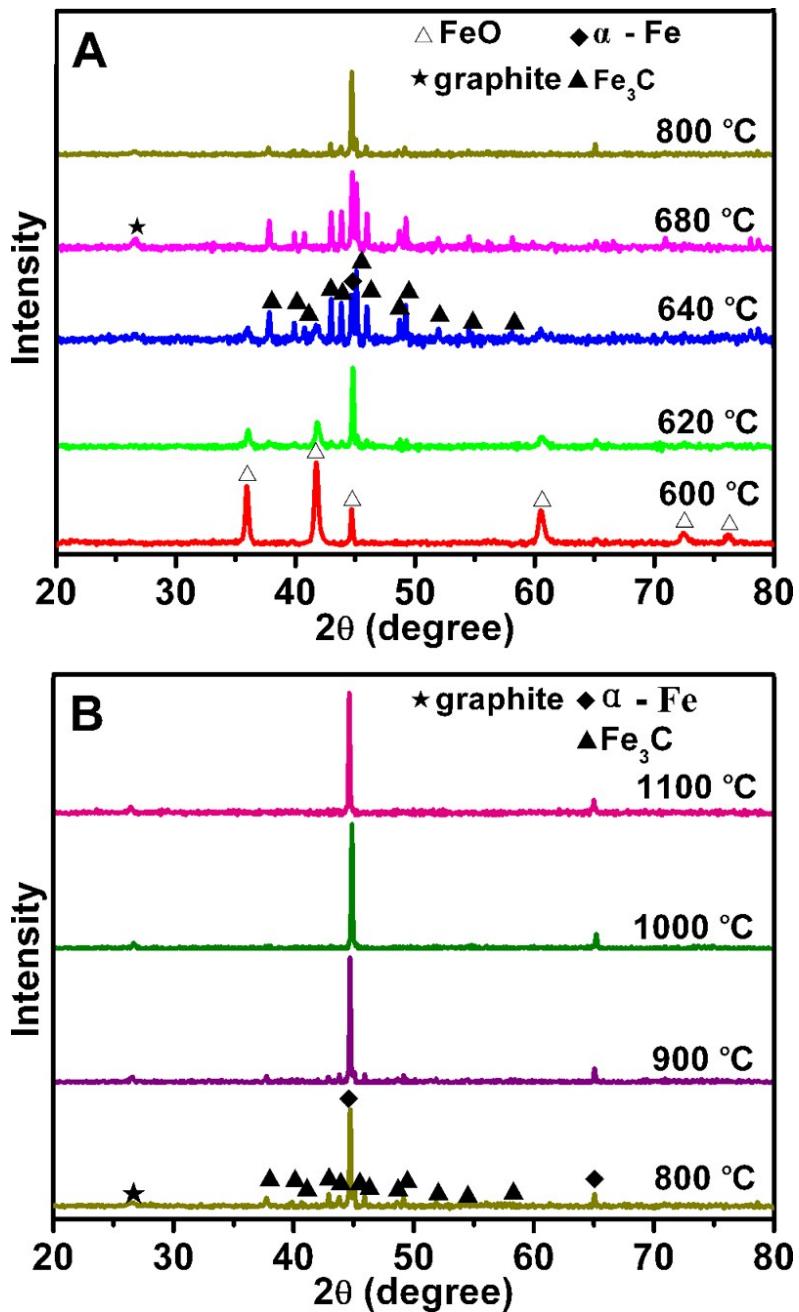


Fig. S5 XRD patterns of the composites derived from CS- Fe^{3+} precursor with the heating temperature of 600~1100 °C.

Table S2. Fitting parameters of the Fe EXAFS spectra based on Fig. 3.

Heating temperature	Shell	N [a]	R (Å) [b]
600°C	Fe-O	2.8 ± 0.5	2.06 ± 0.02
	Fe-Fe	11.0 ± 1.1	3.06 ± 0.01
	Fe-Fe	8.3 ± 1.1	4.33 ± 0.03
620°C	Fe-C/O	2.2 ± 0.2	2.08 ± 0.02
	Fe-Fe	2.1 ± 0.4	2.52 ± 0.01
	Fe-Fe	5.2 ± 0.6	3.12 ± 0.05
680°C	Fe-C	0.4 ± 0.1	1.87 ± 0.02
	Fe-Fe	7.2 ± 0.4	2.51 ± 0.01
	Fe-Fe	9.3 ± 1.7	4.07 ± 0.01
800°C	Fe-Fe	3.1 ± 0.4	2.43 ± 0.01
	Fe-Fe	2.5 ± 0.3	2.81 ± 0.01
	Fe-Fe	6.3 ± 0.4	4.06 ± 0.01

[a] Coordination number. [b] Distance between absorber and backscatterer atoms.

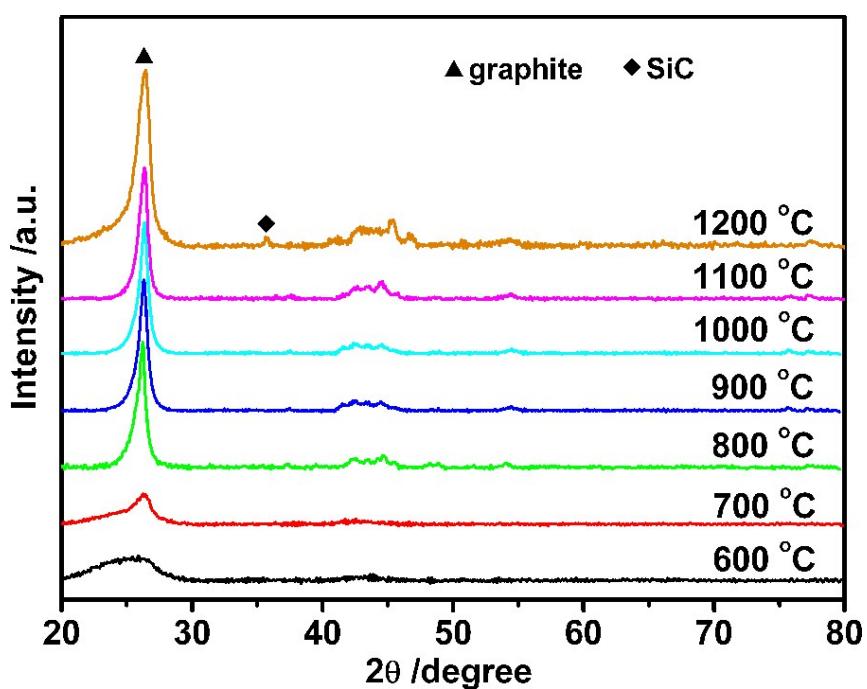


Fig. S6 XRD patterns of the samples derived from CS- Fe^{3+} precursor with the heating temperature of 600~1200 °C after treating with 10 % HCl.

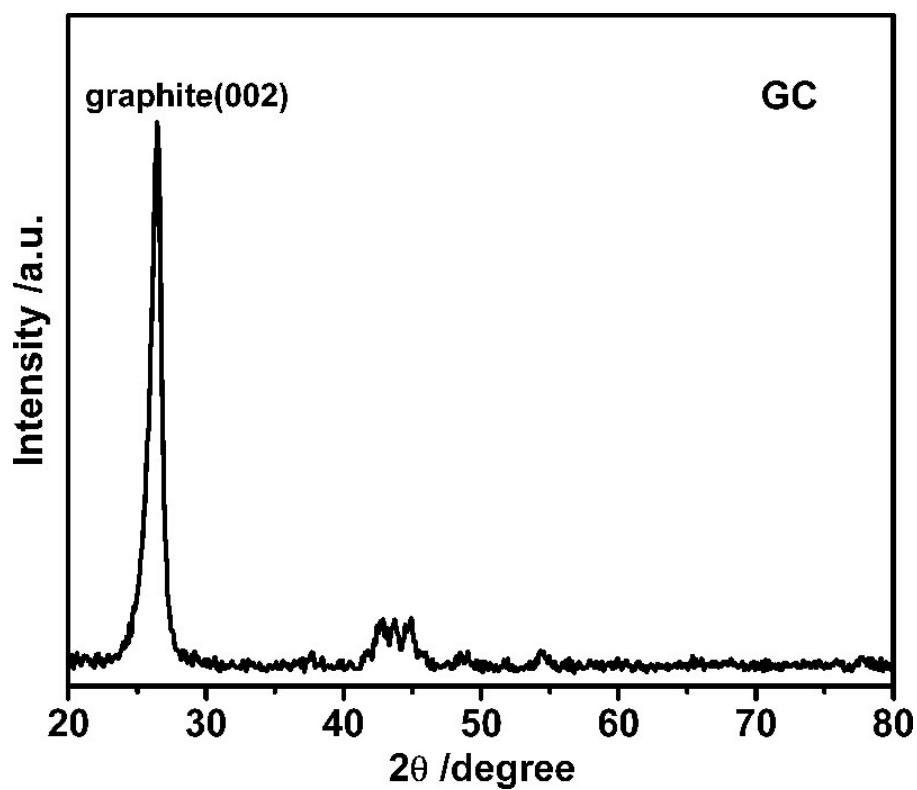


Fig. S7 XRD pattern of GC synthesized from coconut- Fe^{3+} precursor without ceramic chip at a heating temperature of 1400 °C.

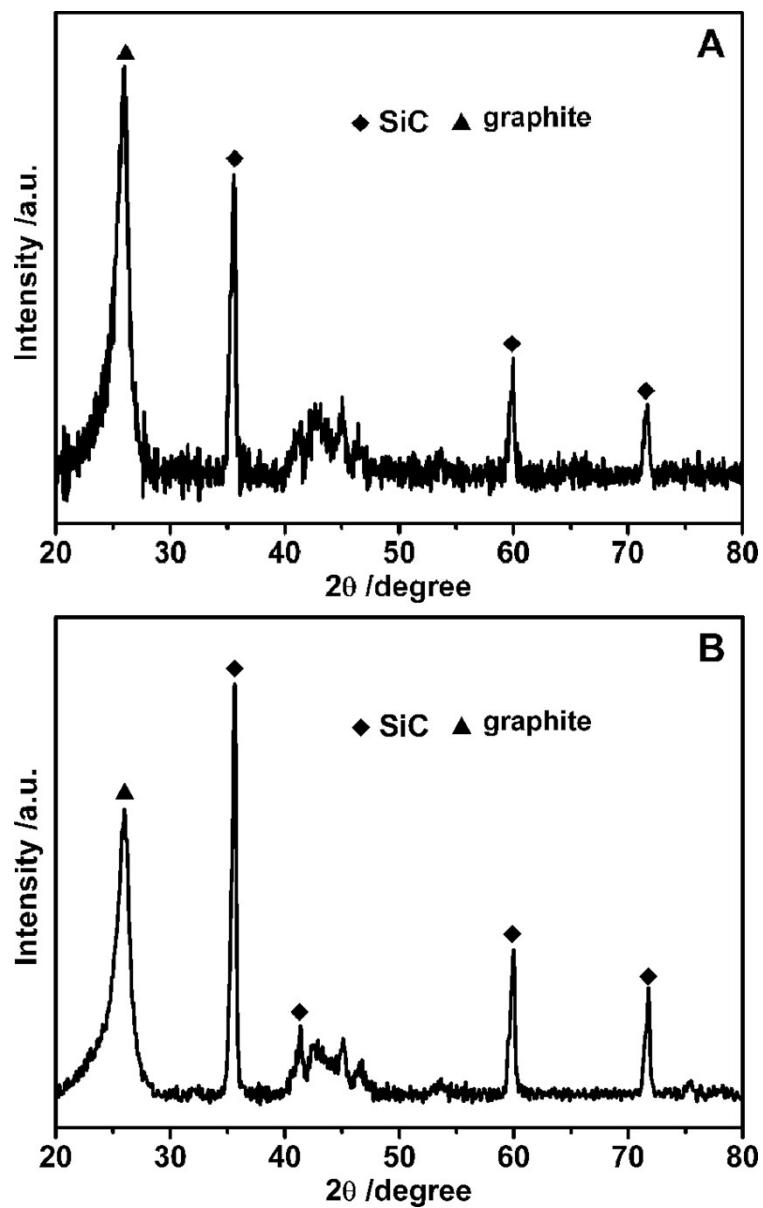
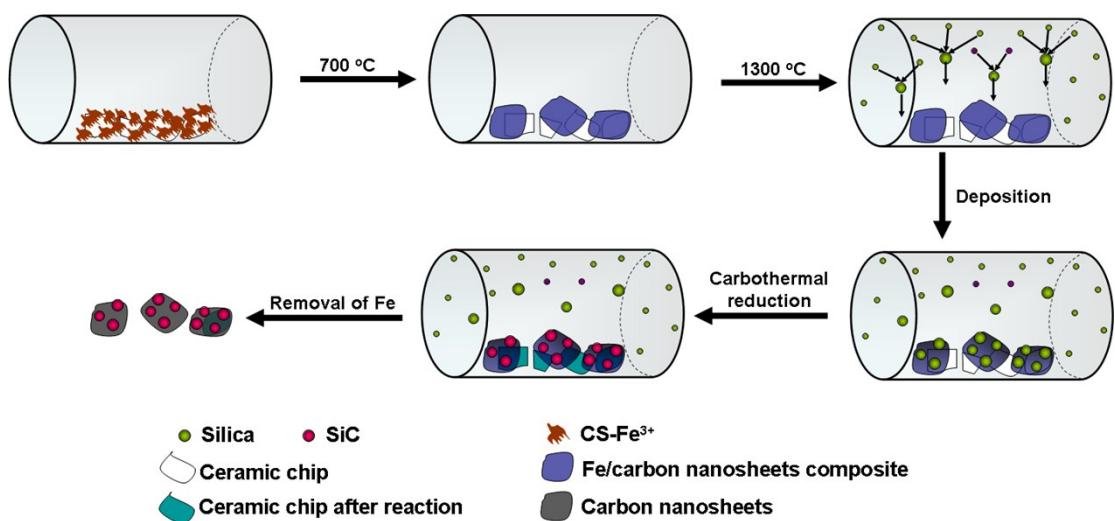
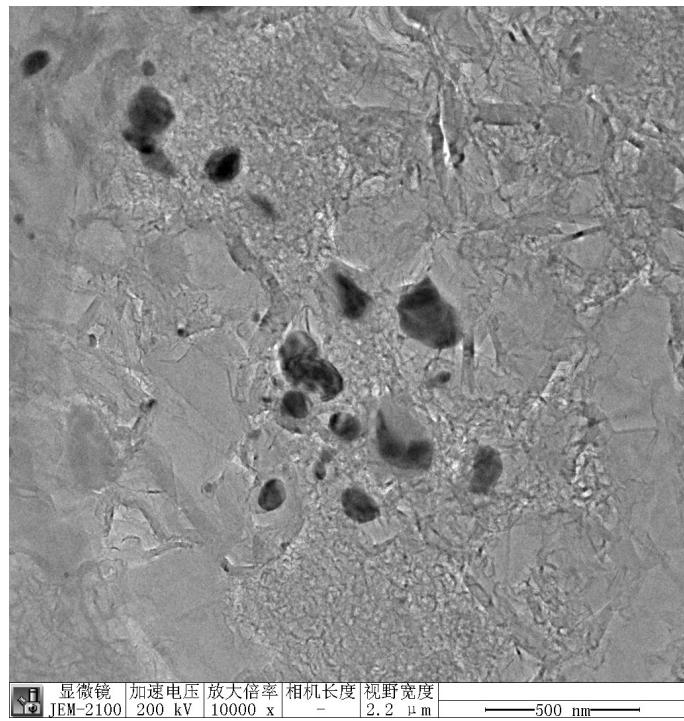


Fig. S8 XRD patterns of (A) SiC/GC-1300 and (B) SiC/GC-1500, respectively.

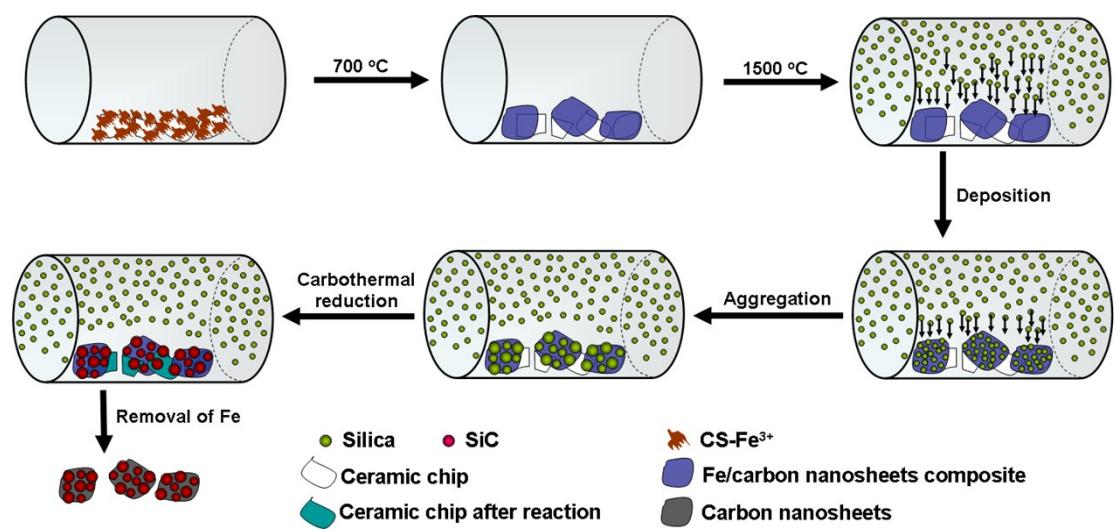


Scheme S1. The supposed formation process of SiC/GC composites synthesized from $1300\text{ }^{\circ}\text{C}$.

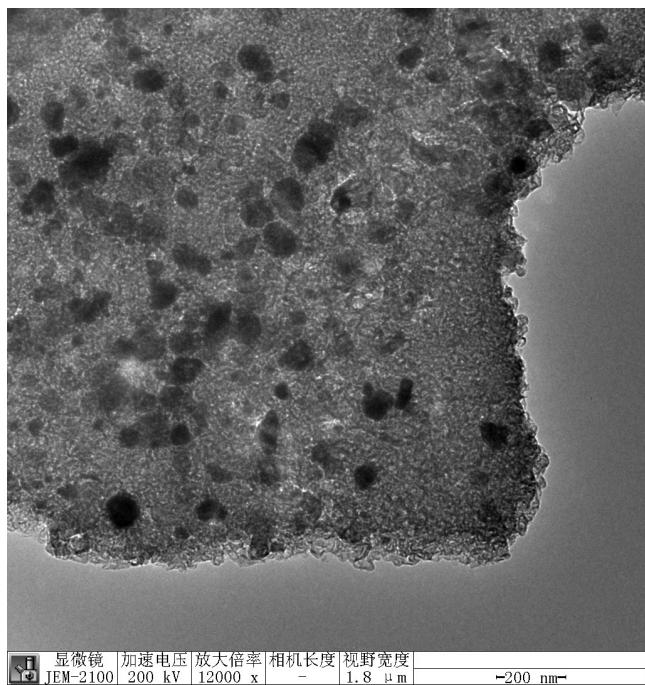


显微镜	JEM-2100	加速电压	200 kV	放大倍率	10000 x	相机长度	-	视野宽度	2.2 μm	—	500 nm
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Fig. S9 TEM images of SiC/GC-1300.



Scheme S2. The supposed formation process of SiC/GC composites synthesized from 1500 °C.



显微镜 JEM-2100 加速电压 200 kV 放大倍率 12000 x 相机长度 - 视野宽度 1.8 μm
-200 nm-

Fig. S10 TEM images of SiC/GC-1500.

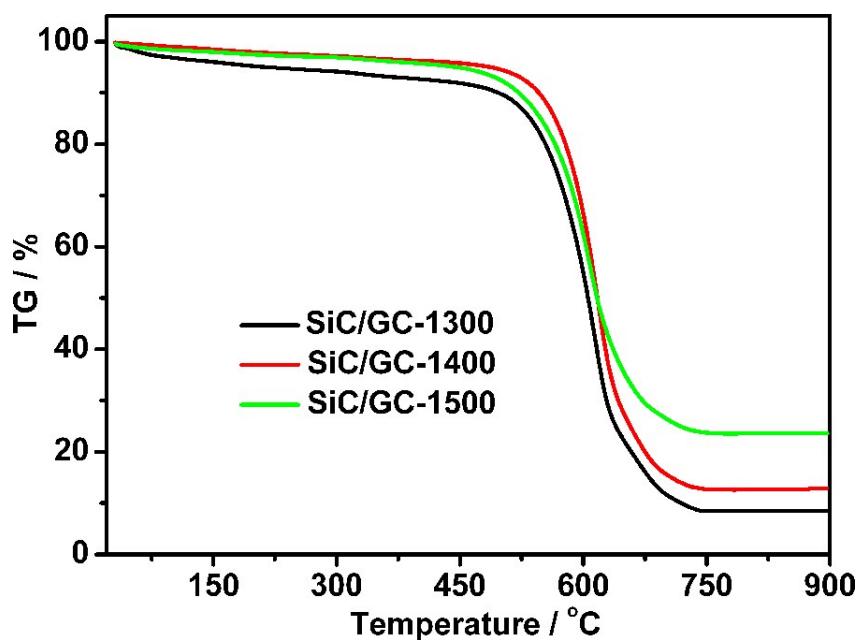


Fig. S11 TG curves of the SiC/GC samples under air synthesized from different temperatures. Notably, SiC/GC-1400 is also called as SiC/GC in this work.

Table S3. SiC content of the SiC/GC samples based on Fig. S11.

Samples	SiC content calculated from TG curves (%)
SiC/GC-1300	5.6
SiC/GC-1400 (SiC/GC)	8.4
SiC/GC-1500	16.1

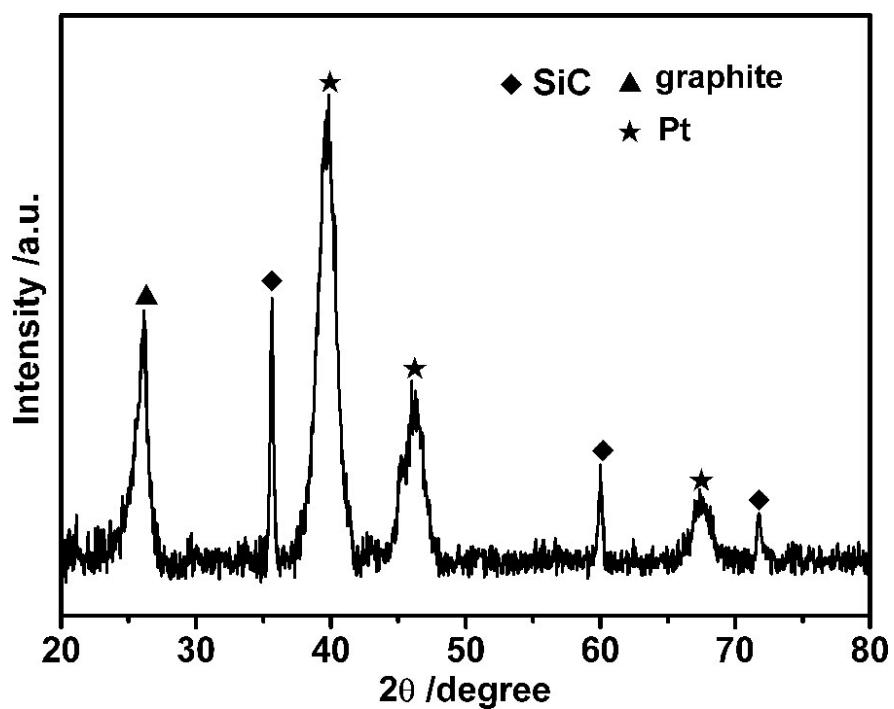


Fig. S12 XRD pattern of Pt-SiC/GC composite.

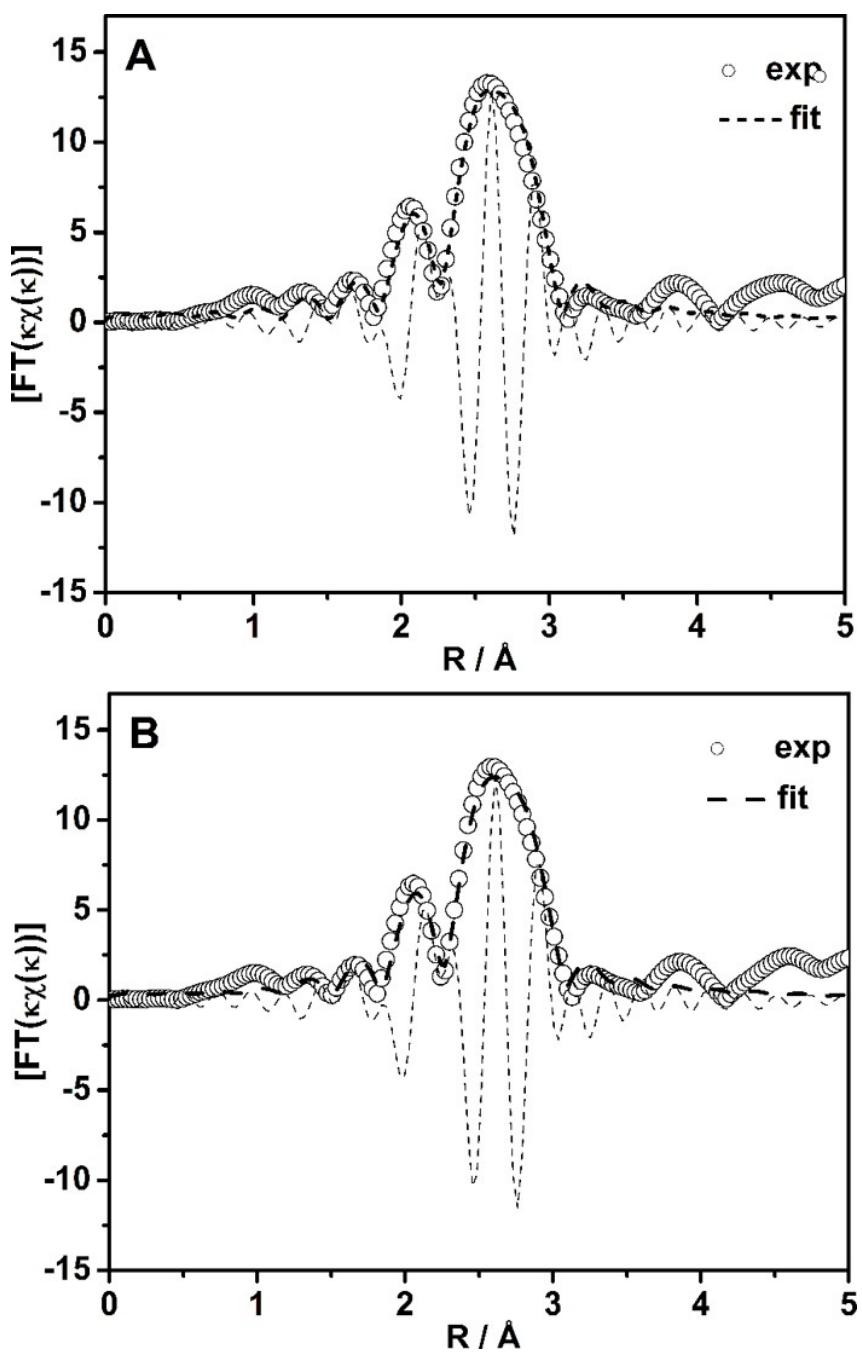


Fig. S13 Fourier transforms of experimental data (o) and fit data (—) of Pt L3-edge extended X-ray absorption fine structure (EXAFS) spectra for Pt-SiC/GC and Pt/GC composites.

Table S4. Fitting parameters of EXAFS spectra for Pt foil, Pt /GC and Pt-SiC/GC in Figure 5B.

Sample	shell	N ^[a]	R ^[b]	σ^2 (10 ⁻³ Å ²) ^[c]	ΔE_0 (eV) ^[d]
Pt foil	Pt-Pt	9.84 ± 0.8	2.76 ± 0.02	4.5 ± 0.2	7.82 ± 0.4
Pt/GC	Pt-C	1.15 ± 0.2	2.05 ± 0.3	2.1 ± 0.4	15.8 ± 0.6
	Pt-Pt	8.28 ± 0.1	2.82 ± 0.06	6.3 ± 0.7	9.72 ± 1.4
P-SiC/GC	Pt-C	2.04 ± 0.5	2.13 ± 0.04	2.6 ± 3.0	9.48 ± 0.1
	Pt-Pt	9.22 ± 0.2	2.75 ± 0.06	0.6 ± 0.1	8.12 ± 0.9

[a] Coordination number. [b] Distance between absorber and backscatterer atoms. [c] Debye–Waller factor. [d] Inner potential correction. Error bounds (accuracies) characterizing the structural parameters obtained by EXAFS spectroscopy are estimated as follows: coordination number N±20%; distance R±0.02, Debye–Waller factor σ^2 ±10%; and inner potential correction ΔE_0 ±20%.

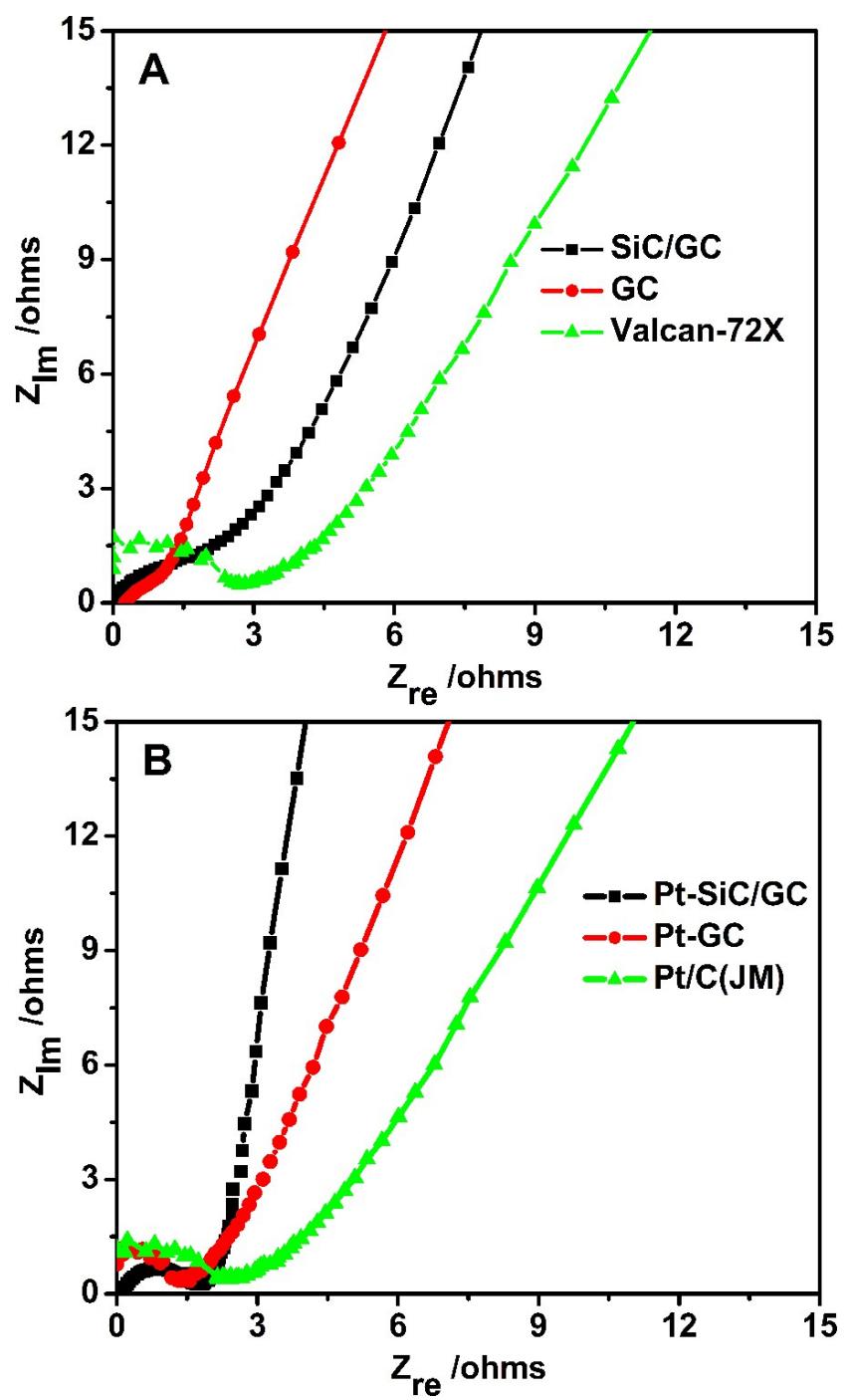


Fig. S14 Electrochemical impedance spectra (EIS) of (A) SiC/GC, GC, Vulcan-72X supports, and (B) Pt-SiC/GC, Pt/GC, Pt/C catalysts tested in 0.5 M H₂SO₄ + 0.5 M CH₃OH electrolyte.

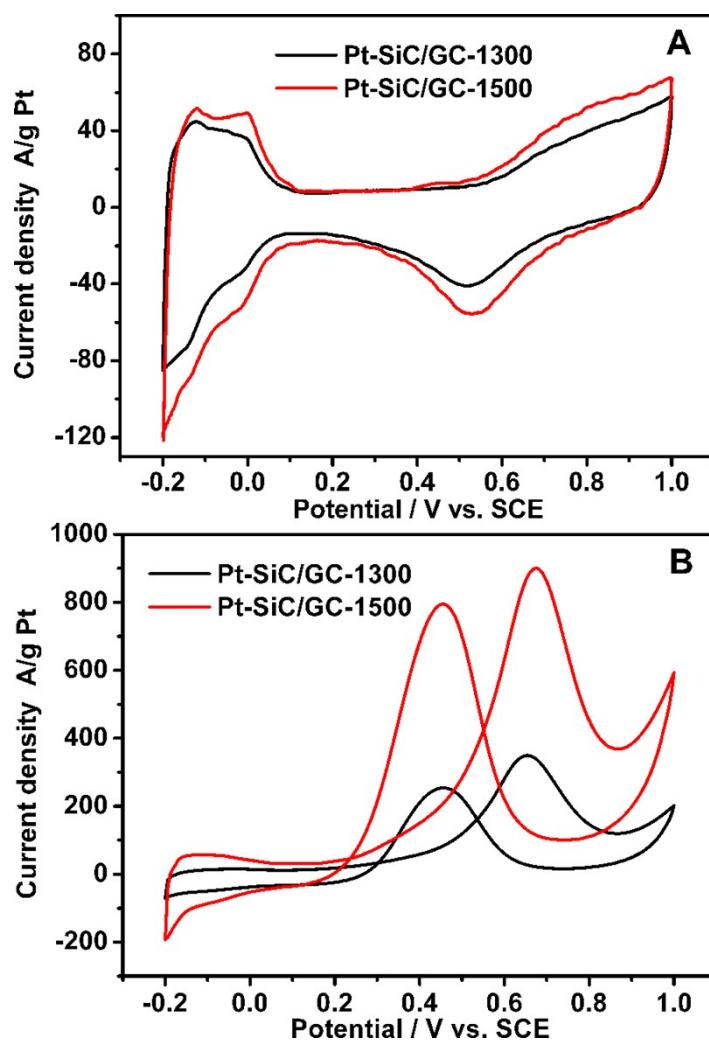


Fig. S15 Electrochemical performances of Pt-SiC/GC-1300 and Pt-SiC/GC-1500 catalysts: The CV curves in 0.5 M H_2SO_4 electrolyte (A) and 0.5 M $\text{H}_2\text{SO}_4 + 0.5 \text{ M CH}_3\text{OH}$ electrolyte (B), respectively.

Table S5 The electrochemical performance of the catalysts.

Catalysts	ECSA (A/g Pt)	Peak potential (V)	Mass current density (A/g Pt)	I_f/I_b
Pt-SiC/GC-1300	61.9	0.67	353.8	1.32
Pt-SiC/GC-1500	74.5	0.68	902.3	1.11
Pt-SiC/C	52.3	0.70	217.1	0.89

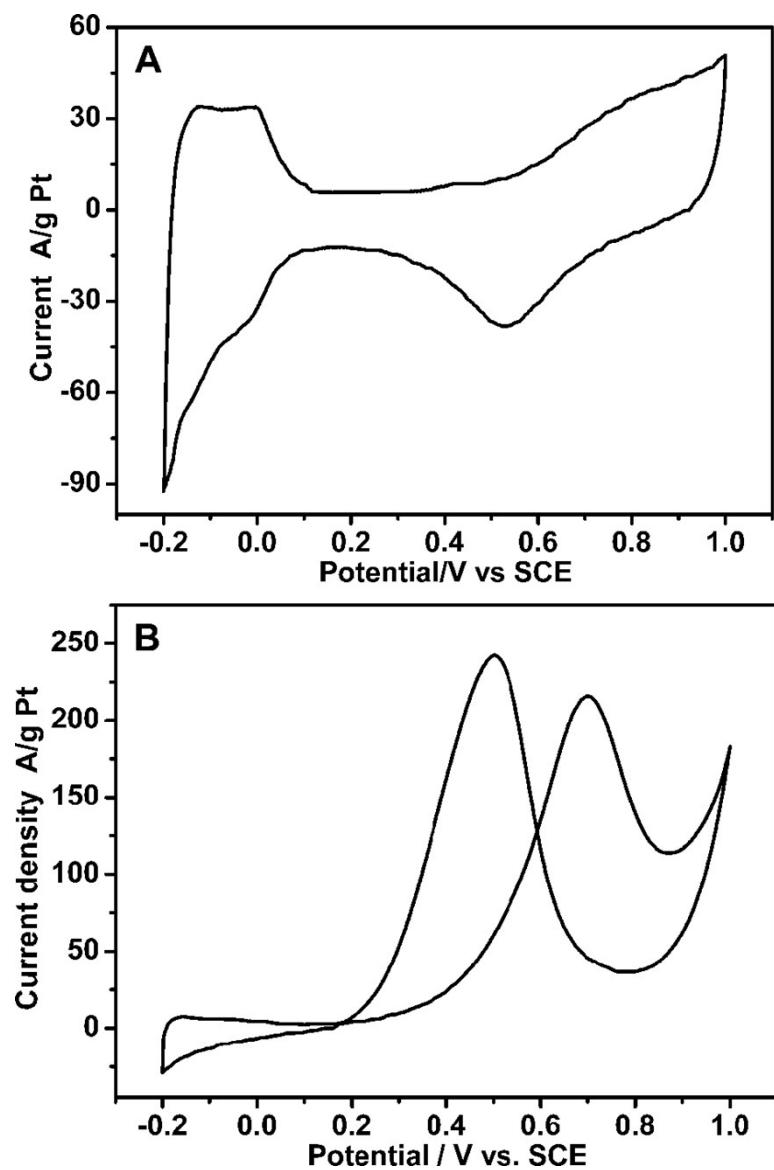


Fig. S16 The CV curves of Pt-SiC/C catalyst in (A) 0.5 M H_2SO_4 electrolyte and (B) 0.5 M H_2SO_4 + 0.5 M CH_3OH electrolyte, respectively.

Table S6. The performances of the previous reported carbide (nitride)-based Pt catalysts towards MOR.

No.	Material name	Pt content	ECSA (m ² /g Pt)	Current density (A/g Pt)	Ref.
1	Pt/SiC	32.8 %		42.25	S1
2	Pt–Ti/SiC	32.8 %	107.64	327.84	S1
3	Pt-SiC/porous carbon	20 %	62.5	836.93	S2
4	Pt/SiC		87.9	1008.3	S3
5	Pt-WC/RGO	5.7 %	253.12	888.8	S4
6	Pt-WC/mesoporous carbon	20 %		784	S5
7	Pt-WC/ordered mesoporous carbon	20 %		367.5	S6
8	Pt-WC/GC	7.5 %		205.6	S7
9	Pt-WC/GC	20.5 %	207.4	1590	S8
10	Pt-WC/GC	37.2 %		1191.8	S9
11	Pt-WC/graphene	7.5 %	103.8	686.6	S10
12	Pt–MoC–GC	36.6 %	55.1	1596.7	S11
13	Pt/NbC nanowires		72.86	766.1	S12
14	P-VC _x /C	34.9 %		~1270	S13
15	Pt/CrN	20 %	82	195	S14
16	Pt/TiC nanowires	19.7 %		348.3	S15
17	Pt–WN/graphene	7.5 %	88.4	531.5	S16
18	Pt-SiC/GC	10 %	147.1	1585.3	This work

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